Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

**Overall Length:** 

0.405 inches

# **Overall Height:**

0.405 inches

**Overall Width:** 

0.437 inches

# **Mounting Facility Quantity:**

1

## Electrode Internally-electrically Connected To Case:

Cathode

#### **Mounting Method:**

Threaded stud

## Features Provided:

## Hermetically sealed case

**Thread Size:** 

0.190 inches

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

1000.0 reverse voltage, peak

## **Current Rating Per Characteristic:**

16.00 amperes forward current, average

## Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

## **Thread Series Designator:**

Unf

## Terminal Type And Quantity:

2 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

#### Unit Of Measure:

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#### **Demilitarization:**

No

# Fiig:

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